SiT5000
Standard Frequency MEMS (VC)TCXO

The Smart Timing Choice™

Features

- 27 standard frequencies between 10 MHz and 40 MHz
- 100% pin-to-pin drop-in replacement to quartz-based (VC)TCXO
- Frequency stability as low as ±5 ppm. Contact SiTime for tighter stability options
- Low phase jitter: 0.5 ps (12 kHz to 20 MHz)
- LVCMOS compatible output with SoftEdge™ option for EMI reduction
- Voltage control, standby, output enable or no connect modes
- Standard 4-pin packages: 2.5 x 2.0, 3.2 x 2.5, 5.0 x 3.2, 7.0 x 5.0 mm
- Outstanding silicon reliability of 2 FIT, 10 times better than quartz
- Pb-free, RoHs and REACH compliant

Applications

- WiFi, 3G, LTE, SDI, Ethernet, SONET, DSL
- Telecom, networking, smart meter, wireless, test instrumentation



Electrical Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Output Frequency Range	f	Refer to the frequency list (*page 6*)			MHz	27 standard frequencies between 10 MHz and 40 MHz
Initial Tolerance	F_init	-1.5	–	+1.5	ppm	At 25°C after two reflows
Stability Over Temperature	F_stab	-5	–	+5	ppm	Over operating temperature range at rated nominal power supply voltage and load. (*see ordering codes on page 6*) **Contact SiTime for tighter stability options.**
Supply Voltage	F_vdd	–	50	–	ppb	±10% Vdd (±5% for Vdd = 1.8V)
Output Load	F_load	–	0.1	–	ppm	15 pF ±10% of load
First year Aging	F_aging	-2.5	–	+2.5	ppm	25°C
10-year Aging		-4.0	–	+4.0	ppm	25°C
Operating Temperature Range	T_use	-20	–	+70	°C	Extended Commercial
		-40	–	+85	°C	Industrial
Supply Voltage	Vdd	1.71	1.8	1.89	V	Contact SiTime for any other supply voltage options.
		2.25	2.5	2.75	V	
		2.52	2.8	3.08	V	
		2.70	3.0	3.3	V	
		2.97	3.3	3.63	V	
Pull Range	PR	±12.5			ppm	
Upper Control Voltage	VC_U	Vdd-0.1	–	–	V	All Vdds. Voltage at which maximum deviation is guaranteed.
Control Voltage Range	VC_L	–	–	0.1	V	
Control Voltage Input Impedance	Z_vc	100	–	–	kΩ	
Frequency Change Polarity	–	Positive slope			–	
Control Voltage -3dB Bandwidth	V_BW	–	–	8	kHz	
Current Consumption	Idd	–	31	33	mA	No load condition, f = 20 MHz, Vdd = 2.5V, 2.8V or 3.3V.
		–	29	31	mA	No load condition, f = 20 MHz, Vdd = 1.8V.
OE Disable Current	I_OD	–	–	31	mA	Vdd = 2.5V, 2.8V or 3.3V, OE = GND, output is Weakly Pulled Down
		–	–	30	mA	Vdd = 1.8 V. OE = GND, output is Weakly Pulled Down
Standby Current	I_std	–	–	70	µA	Vdd = 2.5V, 2.8V or 3.3V, $\overline{ST}$ = GND, output is Weakly Pulled Down.
		–	–	10	µA	Vdd = 1.8V. $\overline{ST}$ = GND, output is Weakly Pulled Down.
Duty Cycle	DC	45	–	55	%	All Vdds
LVCMOS Rise/Fall Time	Tr, Tf	–	1.5	2	ns	LVCMOS option. Default rise/fall time, All Vdds, 10% - 90% Vdd.
SoftEdge™ Rise/Fall Time		SoftEdge™ Rise/Fall Time Table			ns	SoftEdge™ option. Frequency and supply voltage dependent.
Output Voltage High	VOH	90%	–	–	Vdd	OH = -7 mA, IOL = 7 mA, (Vdd = 3.3V, 3.0V) IOH = -4 mA, IOL = 4 mA, (Vdd = 2.8V, 2.5V) IOH = -2 mA, IOL = 2 mA, (Vdd = 1.8V)
Output Voltage Low	VOL	–	–	10%	Vdd	
Input Voltage High	VIH	70%	–	–	Vdd	Pin 1, OE or $\overline{ST}$
Input Voltage Low	VIL	–	–	30%	Vdd	Pin 1, OE or $\overline{ST}$
Input Pull-up Impedance	Z_in	–	100	250	kΩ	

Electrical Characteristics (continued)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Startup Time	T_start	–	–	10	ms	Measured from the time Vdd reaches its rated minimum value
OE Enable/Disable Time	T_oe	–	–	150	ns	f = 80 MHz. For other frequencies, T_oe = 100 ns + 3 cycles
Resume Time	T_resume	–	6	10	ms	Measured from the time ST pin crosses 50% threshold
RMS Period Jitter	T_jitt	–	1.7	2	ps	f = 10 MHz, Vdd = 2.5V, 2.8V or 3.3V
		–	1.7	2	ps	f = 10 MHz, Vdd = 1.8V
RMS Phase Jitter (random)	T_phj	–	0.5	1	ps	f = 10 MHz, Integration bandwidth = 12 kHz to 20 MHz, All Vdds

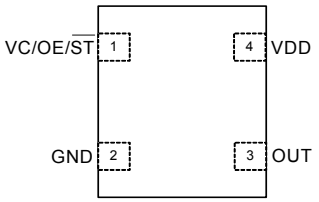
Note:

1. All electrical specifications in the above table are measured with 15pF output load, Contact SiTime for higher drive options.

Pin Configuration

Pin	Symbol	Functionality	
1	VC/OE/$\overline{ST}$/NC	V control	Voltage control
		Output Enable	H or Open[2]: specified frequency output L: output is high impedance. Only output driver is disabled.
		Standby	H or Open[2]: specified frequency output L: output is low (weak pull down). Device goes to sleep mode. Supply current reduces to I_std.
		NC	No connect (input receiver off)
2	GND	Power	Electrical and case ground
3	CLK	Output	Oscillator output
4	VDD	Power	Power supply voltage

Top View



Note:

2. A pull-up resistor of <10 k? between OE/ $\overline{ST}$ pin and Vdd is recommended in high noise environment when the device operates in OE/$\overline{ST}$ mode.

Absolute Maximum

Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-65	150	°C
VDD	-0.5	4	V
Electrostatic Discharge	–	2000	V
Soldering Temperature (follow standard Pb free soldering guidelines)	–	260	°C

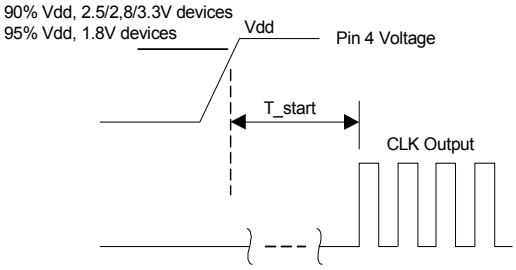
Thermal Consideration

Package	θJA, 4 Layer Board (°C/W)	θJA, 2 Layer Board (°C/W)	θJC, Bottom (°C/W)
7050	191	263	27
5032	97	199	24
3225	109	212	27
2520	117	222	26

Environmental Compliance

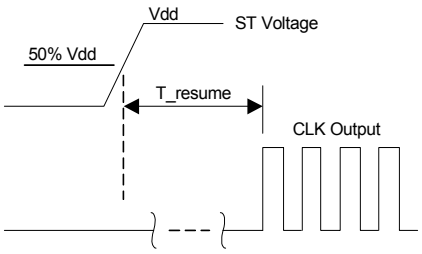
Parameter	Condition/Test Method
Mechanical Shock	**MIL-STD-883F, Method 2002**
Mechanical Vibration	**MIL-STD-883F, Method 2007**
Temperature Cycle	**JESD22, Method A104**
Solderability	**MIL-STD-883F, Method 2003**
Moisture Sensitivity Level	**MSL1 @ 260°C**

Timing Diagram



T_start: Time to start from power-off

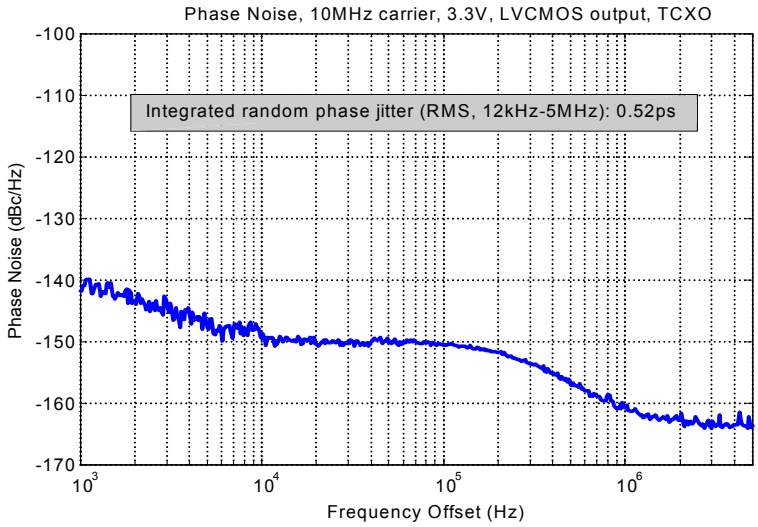
(ST/OE Mode)



T_resume: Time to resume from ST

(ST Mode Only)

Phase Noise Plot



SoftEdge™ Option

The SoftEdge™ output is available as a standard option for the SiT500x family of MEMS (VC)TCXOs. It is typically used for EMI reduction similar to that of the clipped sinewave output common to many quartz based TCXOs.

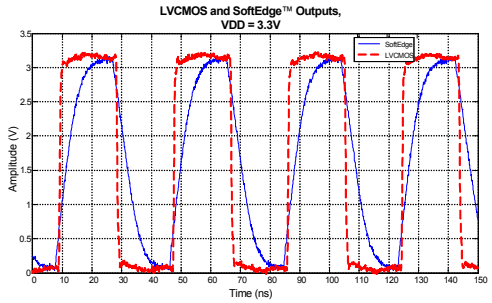
In the SoftEdge™ mode, the slower rise/fall edges of the output waveform reduce the higher clock harmonics in a digital clock signal, minimizing EMI radiation at these harmonics. The table below show the actual rise/fall time in relation to the desired output frequency and the supply voltage with a 10 kΩ / 10 pF load. Rail-to-rail swing of the output is maintained for these supported frequencies.

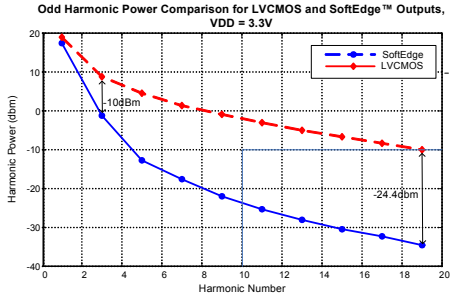
Rise/Fall Time for SoftEdge™ Option

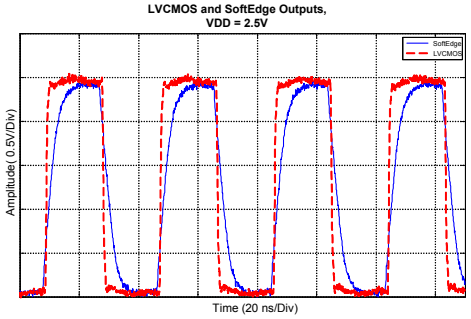
Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Rise/Fall Time	Tr, Tf	4.0	6.5	9.5	ns	1-26 MHz, 1.8V, 3.0 and 3.3V, MHz 10k and 10 pF, 20%-80% Vd
		2.5	4.0	6.0	ns	1-26 MHz, 2.5V and 2.8V, MHz 10k and 10 pF, 20%-80% Vdd
		1.5	3.5	5.0	ns	26-40 MHz, 1.8V, 3.0V and 3.3V, MHz 10k and 10 pF, 20%-80% Vdd
		1.5	2.5	4.5	ns	26-40 MHz, 2.5V and 2.8V, MHz 10k and 10 pF, 20%-80% Vdd

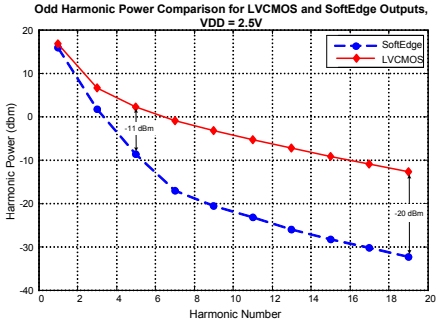
SoftEdge™ Waveform Examples and Corresponding Harmonics Reduction

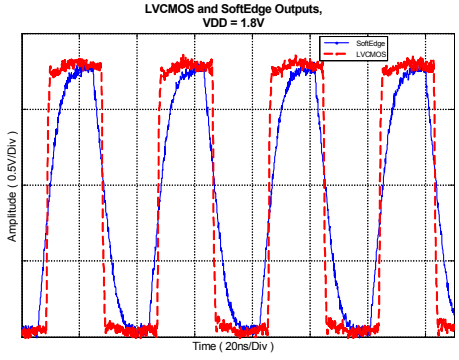
Figures below illustrate the harmonic power reduction as the rise/fall times are slowed from the standard squarewave output to that of the SoftEdge™ output. In general, the 1.8V device shows the lowest harmonics and provides best EMI performance comparing to devices with higher operating voltages.

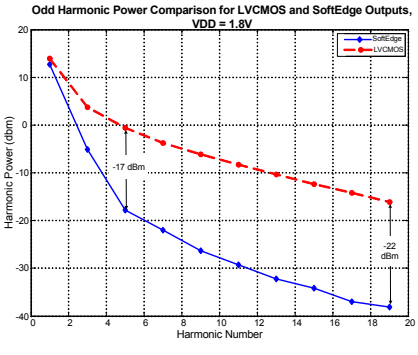




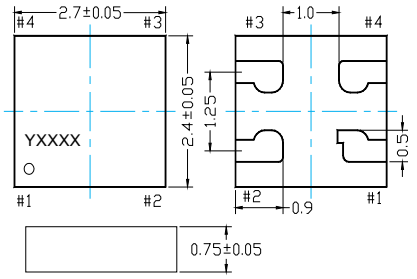
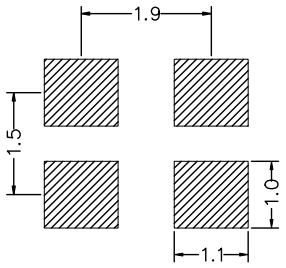
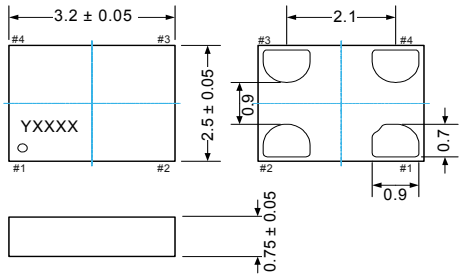
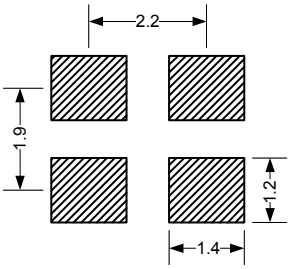
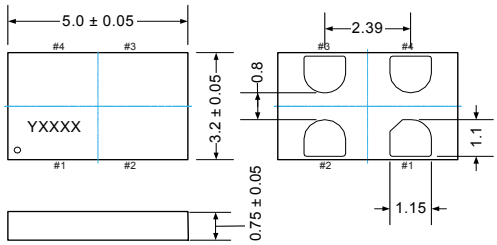
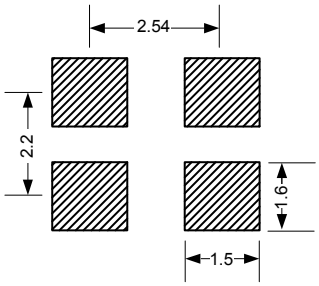
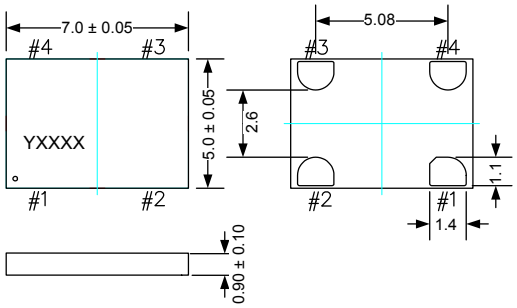
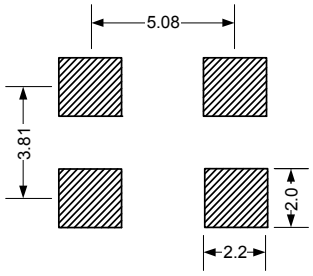








Dimensions and Patterns

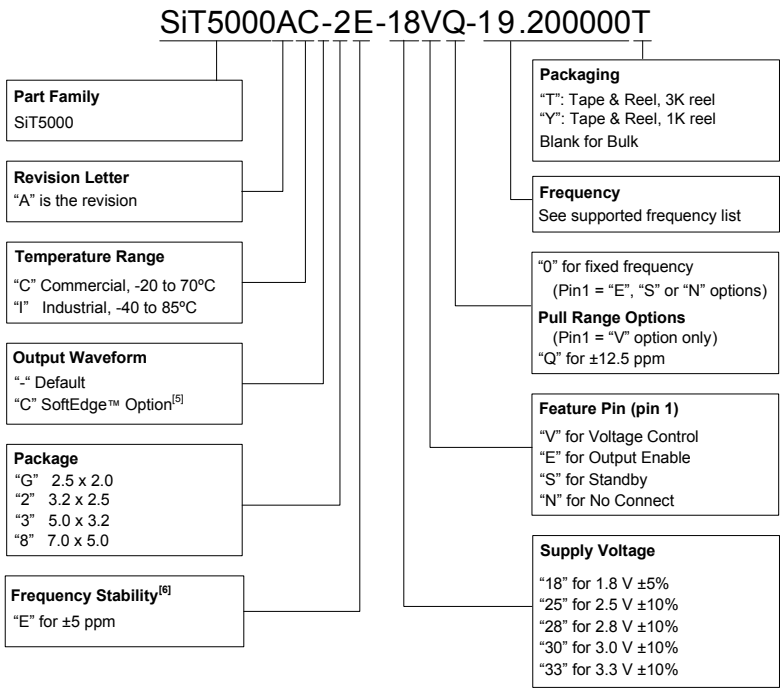
Package Size – Dimensions (Unit: mm) [3]	Recommended Land Pattern (Unit: mm) [4]
2.7 x 2.4 x 0.75 mm (100% compatible with 2.5 x 2. 0 mm footprint)	
	
3.2 x 2.5 x 0.75 mm	
	
5.0 x 3.2 x 0.75 mm	
	
7.0 x 5.0 x 0.90 mm	
	

Notes:

3. Top marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.
4. A capacitor of value 0.1 μF between Vdd and GND is recommended.

Ordering Information

The Part No. Guide is for reference only. To customize and build an exact part number, use the SiTime Part Number Generator.



Notes:

5. SiTime's SoftEdge™ output waveform with 6 ns rise/fall time reduces EMI and is similar to clipped sine wave in functionality.
6. Contact SiTime for tighter stability options.

Supported Frequencies

10 MHz	12 MHz	12.288 MHz	12.8 MHz	13 MHz	14 MHz	14.4 MHz	14.7456 MHz	16 MHz
16.357 MHz	16.3676 MHz	16.367667 MHz	16.368 MHz	16.369 MHz	16.8 MHz	19.2 MHz	19.44 MHz	19.68 MHz
20 MHz	20.8 MHz	24 MHz	25 MHz	26 MHz	27.456 MHz	33.6 MHz	38.4 MHz	40 MHz

Additional Information

Document	Description	Download Link
Manufacturing Notes	Tape & Reel dimension, reflow profile and other manufacturing related info	http://www.sitime.com/component/docman/doc_download/85-manufacturing-notes-for-sitime-oscillators
Qualification Reports	RoHS report, reliability reports, composition reports	http://www.sitime.com/support/quality-and-reliability
Performance Reports	Additional performance data such as phase noise, current consumption and jitter for selected frequencies	http://www.sitime.com/support/performance-measurement-report
Termination Techniques	Termination design recommendations	http://www.sitime.com/support/application-notes
Layout Techniques	Layout recommendations	http://www.sitime.com/support/application-notes

Revision History

Version	Release Date	Change Summary
1.0	11/12/15	Final production release • Revised initial tolerance, stability over temperature and first/10 year aging values in the electrical characteristics table • Revised frequency stability option

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Supplemental Information

The Supplemental Information section is not part of the datasheet and is for informational purposes only.

Silicon MEMS Outperforms Quartz

Silicon MEMS Outperforms Quartz

The Smart Timing Choice™

Best Reliability

Silicon is inherently more reliable than quartz. Unlike quartz suppliers, SiTime has in-house MEMS and analog CMOS expertise, which allows SiTime to develop the most reliable products. Figure 1 shows a comparison with quartz technology.

Why is SiTime Best in Class:

- SiTime's MEMS resonators are vacuum sealed using an advanced EpiSeal™ process, which eliminates foreign particles and improves long term aging and reliability
- World-class MEMS and CMOS design expertise

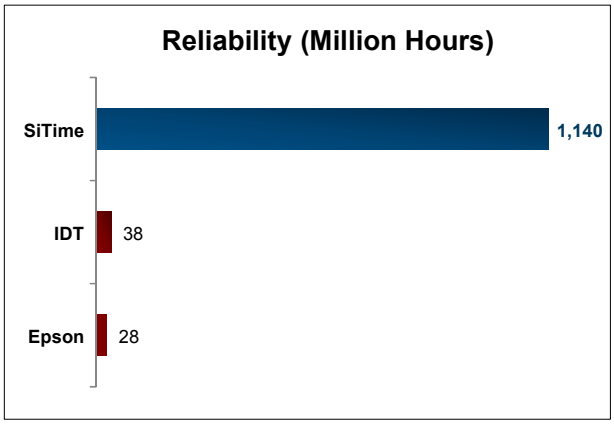


Figure 1. Reliability Comparison[1]

Best Aging

Unlike quartz, MEMS oscillators have excellent long term aging performance which is why every new SiTime product specifies 10-year aging. A comparison is shown in Figure 2.

Why is SiTime Best in Class:

- SiTime's MEMS resonators are vacuum sealed using an advanced EpiSeal process, which eliminates foreign particles and improves long term aging and reliability
- Inherently better immunity of electrostatically driven MEMS resonator

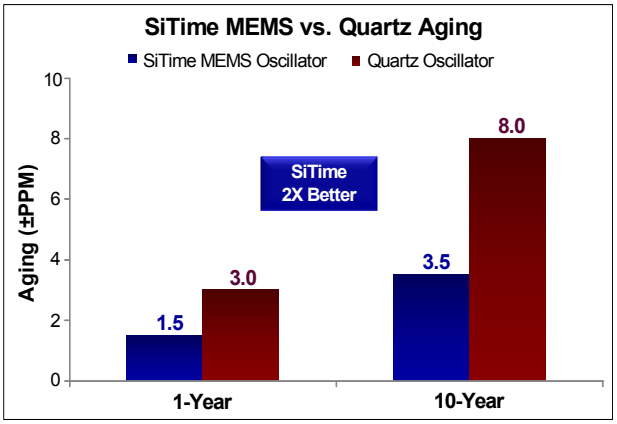


Figure 2. Aging Comparison[2]

Best Electro Magnetic Susceptibility (EMS)

SiTime's oscillators in plastic packages are up to 54 times more immune to external electromagnetic fields than quartz oscillators as shown in Figure 3.

Why is SiTime Best in Class:

- Internal differential architecture for best common mode noise rejection
- Electrostatically driven MEMS resonator is more immune to EMS

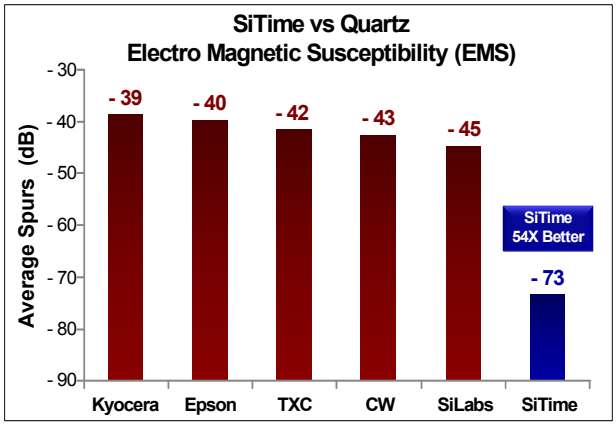


Figure 3. Electro Magnetic Susceptibility (EMS)[3]

Best Power Supply Noise Rejection

SiTime's MEMS oscillators are more resilient against noise on the power supply. A comparison is shown in Figure 4.

Why is SiTime Best in Class:

- On-chip regulators and internal differential architecture for common mode noise rejection
- Best analog CMOS design expertise

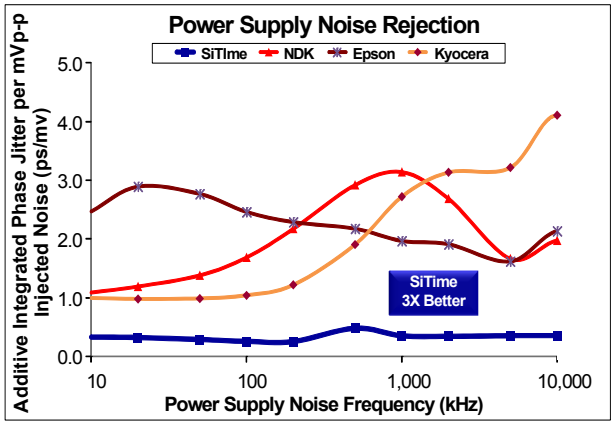


Figure 4. Power Supply Noise Rejection[4]

Best Vibration Robustness

High-vibration environments are all around us. All electronics, from handheld devices to enterprise servers and storage systems are subject to vibration. Figure 5 shows a comparison of vibration robustness.

Why is SiTime Best in Class:

- The moving mass of SiTime's MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

Best Shock Robustness

SiTime's oscillators can withstand at least 50,000 *g* shock. They all maintain their electrical performance in operation during shock events. A comparison with quartz devices is shown in Figure 6.

Why is SiTime Best in Class:

- The moving mass of SiTime's MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

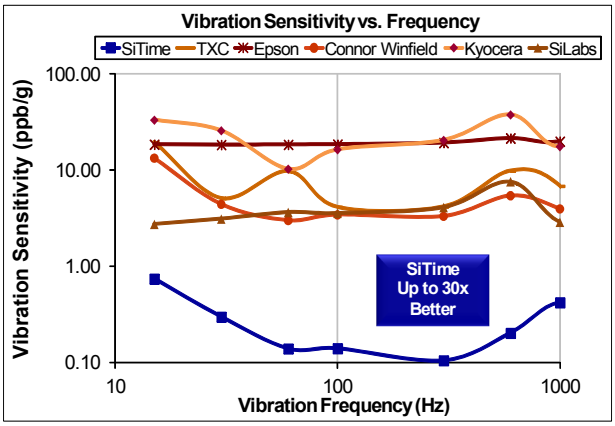


Figure 5. Vibration Robustness[5]

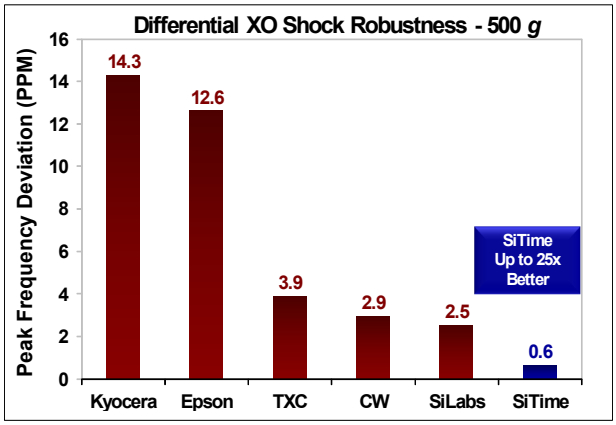


Figure 6. Shock Robustness[6]

Notes:

1. Data Source: Reliability documents of named companies.
2. Data source: SiTime and quartz oscillator devices datasheets.
3. Test conditions for Electro Magnetic Susceptibility (EMS):
   - According to IEC EN61000-4.3 (Electromagnetic compatibility standard)
   - Field strength: 3V/m
   - Radiated signal modulation: AM 1 kHz at 80% depth
   - Carrier frequency scan: 80 MHz – 1 GHz in 1% steps
   - Antenna polarization: Vertical
   - DUT position: Center aligned to antenna

   Devices used in this test:
   SiTime, SiT9120AC-1D2-33E156.250000 - MEMS based - 156.25 MHz
   Epson, EG-2102CA 156.2500M-PHPAL3 - SAW based - 156.25 MHz
   TXC, BB-156.250MBE-T - 3rd Overtone quartz based - 156.25 MHz
   Kyocera, KC7050T156.250P30E00 - SAW based - 156.25 MHz
   Connor Winfield (CW), P123-156.25M - 3rd overtone quartz based - 156.25 MHz
   SiLabs, Si590AB-BDG - 3rd overtone quartz based - 156.25 MHz
4. 50 mV pk-pk Sinusoidal voltage.

   Devices used in this test:
   SiTime, SiT8208AI-33-33E-25.000000, MEMS based - 25 MHz
   NDK, NZ2523SB-25.6M - quartz based - 25.6 MHz
   Kyocera, KC2016B25M0C1GE00 - quartz based - 25 MHz
   Epson, SG-310SCF-25M0-MB3 - quartz based - 25 MHz
5. **Devices used in this test:** same as EMS test stated in Note 3.
6. Test conditions for shock test:
   - MIL-STD-883F Method 2002
   - Condition A: half sine wave shock pulse, 500-g, 1ms
   - Continuous frequency measurement in 100 µs gate time for 10 seconds

   Devices used in this test: same as EMS test stated in Note 3
7. Additional data, including setup and detailed results, is available upon request to qualified customers. Please contact productsupport@sitime.com.

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